



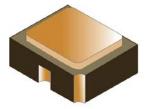
# **Schottky Barrier Diode Ceramic Surface Mount**

Qualified per MIL-PRF-19500/444

<u>Qualified Levels:</u> JAN, JANTX, JANTXV and JANS

#### **DESCRIPTION**

This 1N5711UB and 1N5712UB Schottky barrier diode is ceramic encased and offers military grade qualifications for high-reliability applications. Unidirectional as well as doubler, common anode and common cathode polarities are available.



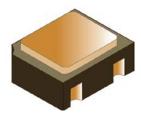
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#### **FEATURES**

- Surface mount equivalent of JEDEC registered 1N5711, 1N5712 numbers.
- JAN, JANTX, JANTXV and commercial qualifications also available per MIL-PRF-19500/444 on "1N" numbers only.

(See Part Nomenclature for all available options).

RoHS compliant by design.



**UB Package** 

# **APPLICATIONS / BENEFITS**

- Low reverse leakage characteristics.
- Low-profile ceramic surface mount package (see package illustration).
- ESD sensitive to Class 1.

# Also available in:

DO-35 package (axial-leaded)

1N5711-1, 1N5712-1, 1N6857-1, and 1N6858-1



(surface mount) 1N5711UR-1, 1N5712UR-1, 1N6857UR-1, and 1N6858UR-1

# MAXIMUM RATINGS @ 25 °C unless otherwise stated

Parameters/Test Conditions		Symbol	Value	Unit
Junction and Storage Temperature		$T_{\text{J}}$ and $T_{\text{STG}}$	-65 to +150	٥C
Thermal Resistance, Junction-to-Solder Pad	$R_{\Theta JSP}$	100	°C/W	
Average Rectified Output Current:				
	1N5711UB <sup>(1)</sup>	Io	33	mA
	1N5712UB <sup>(2)</sup>		75	
Solder Temperature @ 10 s			260	°C

**NOTES:** 1. At  $T_{EC}$  and  $T_{SP}$  = +140 °C, derate  $I_O$  to 0 at +150 °C.

2. At  $T_{EC}$  and  $T_{SP}$  = +130 °C, derate  $I_O$  to 0 at +150 °C.

#### MSC - Lawrence

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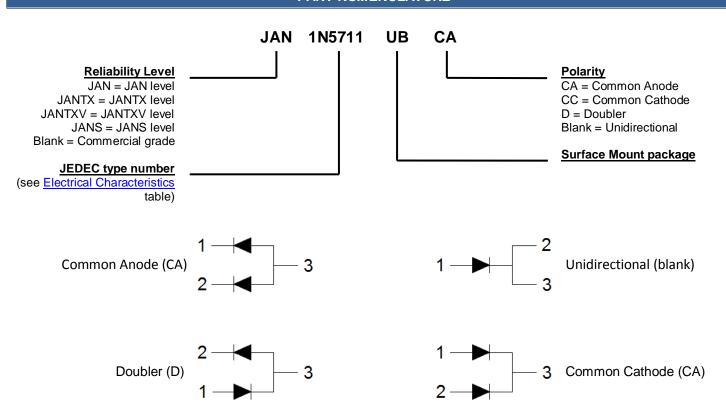
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### **MECHANICAL and PACKAGING**

- CASE: Ceramic.
- TERMINALS: Gold plating over nickel under plate.
- MARKING: Part number, date code, manufacturer's ID.
- TAPE & REEL option: Standard per EIA-418D. Consult factory for quantities.
- WEIGHT: Approximately 0.04 grams.
- See Package Dimensions on last page.

### PART NOMENCLATURE



	SYMBOLS & DEFINITIONS						
Symbol	Definition						
С	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage.						
f	frequency						
$I_R$	Reverse Current: The dc current flowing from the external circuit into the cathode terminal at the specified voltage V <sub>R</sub> .						
Io	Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.						
t <sub>rr</sub>	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs.						
$V_{(BR)}$	Breakdown Voltage: A voltage in the breakdown region.						
V <sub>F</sub>	Forward Voltage: A positive dc anode-cathode voltage the device will exhibit at a specified forward current.						
V <sub>R</sub>	Reverse Voltage: A positive dc cathode-anode voltage below the breakdown region.						
V <sub>RWM</sub>	Working Peak Reverse Voltage: The peak voltage excluding all transient voltages (ref JESD282-B). Also sometimes known historically as PIV.						



# ELECTRICAL CHARACTERISTICS @ 25 °C unless otherwise noted

TYPE NUMBER	MINIMUM MAXIMUM BREAKDOWN FORWARD VOLTAGE VOLTAGE		MAXIMUM WORKING FORWARD PEAK VOLTAGE REVERSE VOLTAGE		MAXIMUM REVERSE LEAKAGE CURRENT		MAXIMUM CAPACITANCE @ V <sub>R</sub> = 0 VOLTS f = 1.0 MHz	
	V <sub>(BR)</sub> @ 10 μA	V <sub>F</sub> @ 1 mA	V <sub>F</sub> @ I <sub>F</sub>	V <sub>RWM</sub>	$I_R @ V_R$		Ст	
	Volts	Volts	V @ mA	V (pk)	nA	Volts	pF	
1N5711UB	70	0.41	1.0 @ 15	50	200	50	2.0	
1N5712UB	20	0.41	1.0 @ 35	16	150	16	2.0	

#### NOTE:

1. Effective minority carrier lifetime  $(\tau)$  is 100 pico seconds.



### **GRAPHS**

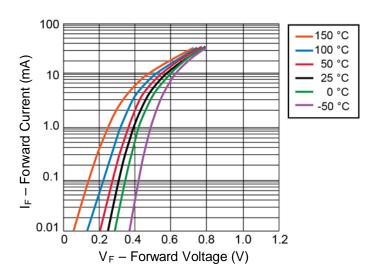


FIGURE 1

I-V Curve showing typical Forward Voltage Variation
Temperature for the 1N5712 Schottky Diodes

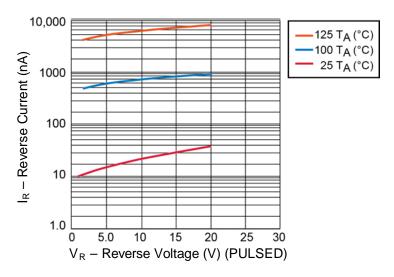


FIGURE 2

1N5712 Typical variation of Reverse

Current (I<sub>R</sub>) vs Reverse Voltage (V<sub>R</sub>) at Various Temperatures



### **GRAPHS**

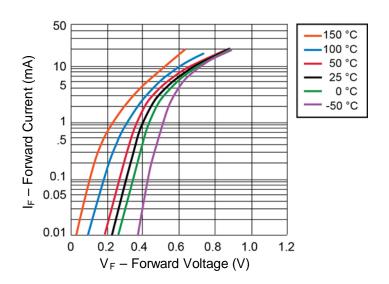


FIGURE 3

I – V curve showing typical Forward Voltage Variation
With Temperature Schottky Diode 1N5711

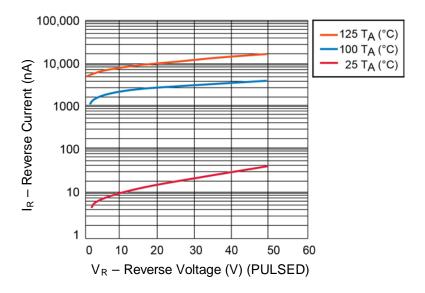


FIGURE 4

1N5711 Typical Variation of Reverse Current (I<sub>R</sub>) vs Reverse Voltage (V<sub>R</sub>)

at Various Temperatures



# GRAPHS

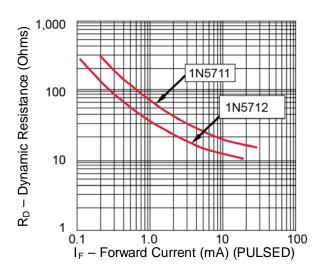
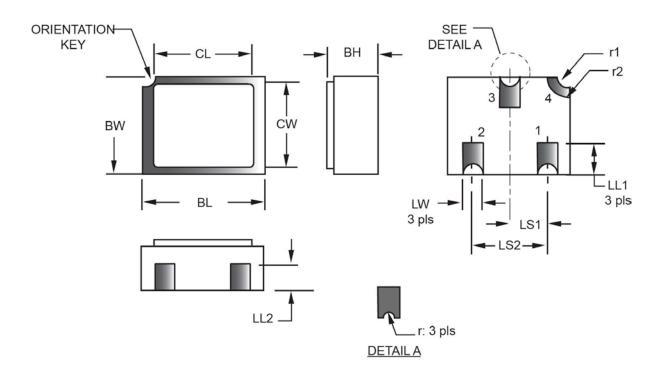


FIGURE 5

Typical Dynamic Resistance ( $R_D$ ) vs Forward Current ( $I_F$ )



### **PACKAGE DIMENSIONS**



Symbol	Dimensions					Dimensions					
	inch		millimeters		Note	Symbol	inch		millimeters		Note
	Min	Max	Min	Max			Min	Max	Min	Max	1
ВН	0.046	0.056	1.17	1.42		LS1	.035	.039	0.89	0.99	
BL	0.115	0.128	2.92	3.25		LS2	.071	.079	1.80	2.01	
BW	0.085	0.108	2.16	2.74		LW	.016	.024	0.41	0.61	
CL	-	0.128	-	3.25		r	-	.008	-	0.20	
CW	-	0.108	-	2.74		r1	-	.012	-	0.31	
LL1	0.022	0.038	0.56	0.97		r2	-	.022	-	.056	
LL2	0.017	0.035	0.43	0.89							

#### **NOTES:**

- 1. Dimensions are in inches. Millimeters are given for information only.
- 2. Ceramic package only.
- 3. Hatched areas on package denote metallized areas.
- 4. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Shielding connected to the lid.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

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JANS1N5712UB/TR JANTXV1N5711UB/TR 1N5712UBCA JANTX1N5712UBCA JANS1N5711UBCC

JANTXV1N5711UBD JANTXV1N5712UBCA JANTX1N5712UBCC JANTX1N5711UBCA JAN1N5711UBD

JANTXV1N5711UBCA JANS1N5711UBCA JANTXV1N5712UBD JANTXV1N5711UBCC JAN1N5712UBCC

JANS1N5711UBD JAN1N5712UBD JANTX1N5712UB JAN1N5711UB JANTXV1N5712UBC JANTXV1N5712UB

JAN1N5712UB JAN1N5712UBCA JAN1N5711UBCA JANTX1N5711UB JANTXV1N5712UBD JAN1N5711UBCC

JANTX1N5711UBC JANTX1N5711UBCA JANTX1N5711UBC JANTXV1N5711UBCC

JANTX1N5711UBCC JANTX1N5711UBD